



# Polar surfaces in a nutshell

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## OUTLINE

- The polar catastrophe
- Electrostatics: micro/macro
- Compensated polar surfaces
- ZnO(0001): Zn-vacancy ordering
- MgO(111): the (2x2) reconstruction
- Ultra-thin MgO(111) films: exotic phases?

#### The polar catastrophe

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## **Polar surfaces: basic electrostatics**

Polar orientations: charged ideal atomic planes  $\rightarrow$  Model of planar capacitors



$$\Delta \phi^{(1)} = \frac{\sigma d}{2\varepsilon_0} = \frac{q}{\varepsilon_0 a} \approx \frac{0.1}{8.9 \times 5.6} \times 10^{-19 + 12 + 10} V \approx 2V$$

The potential drop of a double layer is even bigger than the fundamental gap (note  $\varepsilon_r \sim 10.9$ )

 $\Delta\phi + \Delta\phi' = -\frac{\Delta\phi^{(1)}}{2}$ 

## The « polar catastrophe »

A crystal cannot sustain a macroscopic polarization  $\vec{P}$  in absence of an external electric field

 $\vec{D} = \varepsilon_0 \vec{E} + \vec{P}$  In textbooks: polarization= dipole/unit volume ... Uhm... Nothing is said about the <u>surface charge</u>

Virtually infinite crystal in electrostatic equilibrium

$$<\phi>=cost.$$



Finite (real) crystal at the same electrostatic potential

$$\langle \phi \rangle = cost.$$

Surface charges at the surface of an insulator must be specified in order to set the potential inside a finite sample

$$\langle \vec{P}(\vec{r}) \rangle = \frac{1}{\Omega} \int_{\Omega} d^{3}r \, \vec{P}(\vec{r}) = \frac{1}{\Omega} \int_{\Omega} d^{3}r \, \vec{r} \rho(\vec{r}) + \frac{1}{\Omega} \int_{S} ds \, \vec{r} \left( \vec{P} \cdot \hat{n} \right)$$
*RM. Martin, PRB 9 (1974) 1998*: Bulk contribution: Flux through the surface

#### The polar catastrophe

#### Electrostatics: micro/macro

- Compensated polar surfaces
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- Ultra-thin MgO(111) films: exotic phases?

## A step backward: microscopic/macroscopic

<u>Classical electrostatics</u> Consider fields and other quantities as macroscopic (e.g the « test charge »). <u>Solid state physics</u> deals with microscopic quantities, at the atomic scale.

- Is there any connection ?
- Are Maxwell's equations valid at any scale ?

YES! (to both questions) This can be done through « macroscopic averages »

Microscopic operator (ex. charge density operator)

Microscopic quantity (ex. charge density)

Macroscopic average (convolution with a weight function *w*)

- Macroscopic averages commute with spatial differentiation
- ➔ Maxwell's equations are OK

$$\hat{f} = \sum_{i} q_{i} \,\delta(\vec{r} - \vec{r}_{i})$$

$$f(\vec{r}) = \langle \Psi | \hat{f} | \Psi \rangle$$

$$< f(\vec{r}) > = \frac{1}{\Omega_{0}} \int_{\Omega_{0}} d^{3}r' w(\vec{r}') f(\vec{r} - \vec{r}')$$

$$\frac{\partial < f(\vec{r}) >}{\partial x_{\alpha}} = <\frac{\partial f(\vec{r})}{\partial x_{\alpha}} >$$

## Macroscopic averages: an example

A1 • As Ga  $(AIAs)_3(GaAs)_3$ [100]  $\frac{a_0}{\sqrt{2}}$ (100) superlattice M.Peressi et al, J.Phys.D 31 (1998)  $n(\vec{r})$ **Electron density** contour b) Lateral average 10  $\overline{n}(x)$  $1 \overline{\phi}(x)$ 8  $\bar{f}(x) = \frac{1}{\Delta} \int dy \int dz \ f(x, y, z)$  $<\overline{n}(x)>^{\text{B.04}}$  $< \overline{\phi}(x) >$ Macroscopic average 8.02 8  $<\bar{f}(x)>=\frac{1}{a}\int_{x-\frac{a}{2}}^{x+\frac{a}{2}}dx'\ \bar{f}(x')$ 7.98 -0.1 7.96 -0.2 As Al As Al As Al As Ga As Ga As Ga As

#### The polar catastrophe

Electrostatics: micro/macro

#### Compensated polar surfaces

- ZnO(0001): Zn-vacancy ordering
- MgO(111): the (2x2) reconstruction
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## 1D Polarization (along the surface normal)





The surface charge at the surface/bulk border is related to the bulk dipole moment computed by choosing this border as the origin of the unit cell

## **Electrostatics: multipole expansion**

Let's consider the electrostatic potential in a point r far from a **localized** charge distribution

$$\phi(r,\theta,\varphi) = \sum_{l=0}^{\infty} \sum_{m=-l}^{+l} \frac{4\pi}{2l+1} q_{lm} \frac{1}{r^{l+1}} Y_{lm}(\theta,\varphi)$$

Total charge  $Q \equiv \sqrt{4\pi} q_{00}$ Dipole moment  $\vec{p} = \int d^3x \, \vec{x} \rho(\vec{x})$ 

$$\phi(\vec{r}) = \frac{Q}{r} + \frac{\vec{p} \cdot \vec{r}}{r^3} + \dots$$

 $q_{00} = \sqrt{\frac{1}{4\pi}} \int d^3 x \,\rho(\vec{x})$ 

 $q_{10} = \sqrt{\frac{3}{4\pi}} \int d^3x \, z\rho(\vec{x})$ 

What about crystals ?

They are macroscopic, periodic and virtually infinite systems!

## **Dipole moment and periodic distributions**



#### Theorem:

For a PERIODIC charge distribution, it is ALWAYS possible to choose the origin of the unit cell in order to have a NULL DIPOLE MOMENT

The theorem is independent of the specific form of  $\rho(x)$ 

proof cannot be found in textbooks, but in Goniakowski, Finocchi, Noguera, Rep.Progr.Phys. 71 (2008) 016501 :

## How to avoid the polar catastrophe

Condition for null macroscopic polarization

$$Q_S(x_S) = \frac{\mu_B(x_S)}{a}$$

A simple recipe (there are others):

- 1. Consider formal charges for ions
- 2. Find the origin for zero-dipole unit cell:  $\mu_B = 0$
- 3. If the origin passes through atomic planes (polar surfaces), eliminate the residual surface charge  $Q_s$  (take away some ions or put extra charges)



Take away  $\frac{3}{4}$  surface ions (left) and  $\frac{1}{4}$  surface ions (right)  $\rightarrow$  (2x2) or (4x1) reconstructions, etc.

#### COMPENSATED POLAR SURFACES

- The polar catastrophe
- Electrostatics: micro/macro
- Compensated polar surfaces

#### ZnO(0001): Zn-vacancy ordering

- MgO(111): the (2x2) reconstruction
- Ultra-thin MgO(111) films: exotic phases?

## ZnO(0001)



Compensated surface: -¼ Zn atoms at the surface (or reduce by ~¼ the surface charge)



Clean and stoichiometric (1x1) surface is metallic and not very



FIG. 3. The band structure of the S7 slab. The energy scale is in hartrees (H). The partially occupied Zn-4s band and the unoccupied O-p band are labeled.  $E_f$  denotes the Fermi level of the system.

(1x1) is stabilized in Zn-rich conditions and presence of Hydrogen:

- $\rightarrow$  Adsorption of (coverage ~1/2):
- OH<sup>-</sup>/Zn surface
- H<sup>+</sup> /O surface

Meyer, PRB 69 (2004)



FIG. 4. Schematic diagram of the high-symmetry adsorption sites for OH groups on the Zn-terminated polar ZnO surface. Small/ dark spheres represent Zn, large/gray spheres O atoms.

## ZnO(0001)

Compensated surface: -¼ Zn atoms at the surface (or reduce by ~¼ the surface charge)



Clean surface in UHV: Zn vacancies rearrange

 $\rightarrow$  « triangular reconstructions »

Dulub et al, PRL 90 (2003)



Figure 25. (a) STM image of magic triangles on the Zn-termination; (b), (c) and (d) different atomic models for magic triangles fulfilling the compensation criterion (small white balls: Zn; large dark balls: O); (e) side view of the Zn-terminated surface; (f) STM image of hexagonal holes on the O-termination. Reprinted from [360] with permission from Elsevier, copyright 2002 and from [361] with permission from the American Physical Society, copyright 2003.

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## **Compensated polar surfaces: prototypes**

#### 1. Dissociative water adsorption on MgO(111) [Noguera ('93); Refson('95)]



FIG. 1. (a) Hypothetical hydroxylated (001) surface of MgO, (b) (0001) surface of Mg(OH)<sub>2</sub>, (c) our postulated (111) hydroxyl surface of MgO. The top three O-Mg-O layers of an oxygen-terminated MgO (111) surface have the same structure as  $Mg(OH)_2$  (0001). The (111) hydroxyl surface may be equivalently constructed by protonation of an oxygen-terminated surface or by hydroxylation of a magnesium-terminated surface.

#### 2. The octopole reconstruction of rocksalt(111) [Lacmann('65); Wolf('93)]

Any structure built from a simple cubic cell with 4 anions + 4 cations - "the <u>octopole</u>" - is free from dipole moments.

3-fold coordinated surface atoms on top of triangular pyramids with  $\{100\}$   $\{010\}$  $\{001\}$  facets  $\rightarrow$  (2x2) pattern

#### Non stoichiometric surface

Electrostatic condition for stability is fulfilled



## Pattersson maps of MO(111) surfaces from GIXS



## MgO(111) (2x2) : hex-Mg / MgO



- Can be thought either as <u>a Mg over-layer on the ideal MgO(111)</u> or as a O-spi without the apical O.
- The three surface Mg (A,B,C) are markedly inequivalent
- From the topological (Bader) charges : <u>Mg<sup>(A)</sup> almost neutral</u>



Compensated through <u>anomalous filling</u> : Mg<sup>(A)</sup> almost neutral

Nevertheless, insulating surface -because of the weak  $V_{Mad}$  on Mg(A)

## MgO(111) (2x2) : hex-Mg + O-oct (theory)



→ Minimal (two-phase) model :

hex-Mg for very low  $p_0$ ,

O-oct in more O-rich environments

Also assume they can coexist in variable proportions on the surface

## MgO(111) (2x2) : hex-Mg + O-oct (experience)

 $\odot$  Good fit of the GIXS data with :  $\lambda$  O-oct + (1- $\lambda$ ) hex-Mg (atomic positions and charges taken from the theory - no fitting parameters but  $\lambda$ )



- Minimal (two-phase) model : hex-Mg + O-oct (so far, the best solution)
- Neither theory nor experiments (taken separately) could explain the (2x2) reconstruction in terms of a comprehensive structural model

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## "Uncompensated" polarity in ultra-thin dielectric films grown along a polar direction

Finite number N of atomic layers

- → No « bulk » polarization
- ➔ Sustainable layer dipole ?

$$\Delta \phi \cong N \Delta \phi^{(1)} < E_G$$

- Existence of a critical size N<sub>C</sub> beyond which the film is no more insulator
- Size-sensitive electronic properties



Figure 30. Sketch of the electronic structure of ultra-thin films in their low and high thickness regimes. 1st and *N*th bilayer correspond, respectively, to cation- and anion-terminated film surfaces. Filled and empty electronic states are represented in black and white, respectively.  $E_{\rm F}$  denotes the Fermi level. Reprinted

## MgO: phase diagram (bulk)



Bulk:  $B_1$ (rocksalt) more stable than Bk (hex) However, the (111) surface is polar for  $B_1$  while (0001) non polar in Bk

## **MgO: polarity of different structures**



## MgO: phase diagram of free-standing films

Hexagonal  $B_k$  (0001) more stable for N<30

B1 (2x2) octopole more stable for N>30



➔ By keeping the planar hexagonal symmetry, there might be structural changes as a function of the slab thickness

## MgO(111) / Ag(111) thin films



(1x1) interface:

 $(2\sqrt{3} \times 2\sqrt{3})$  R30° interface:

MgOB1-Ag: lattice mismatch = 3.6%MgOB3-Ag: lattice mismatch = 10.8%MgOB<sub>k</sub>-Ag lattice mismatch = 20.2% MgOB1-Ag: lattice mismatch = 10.8%MgOB3-Ag: lattice mismatch = 2.6%MgOB<sub>k</sub>-Ag lattice mismatch = 4.9%

No means to simulate a fully relaxed interface.  $(2\sqrt{3} \times 2\sqrt{3}) R30^{\circ}$  interface is nevertheless much more stable than (1x1)

		11	ML	2ML				3ML			
	$(2\sqrt{3} \times 2\sqrt{3})$ (1x1)			$(2\sqrt{3} \times 2\sqrt{3})$ (1x			1) (2	$(2\sqrt{3} \times 2\sqrt{3})$ (1x1)			
hex(0001)	(	0.0	3.0		0.2	5.3	}	0.3		8.4	
fcc(111)	(	0.0	3.0		1.0	5.0	3	2.1		7.9	A.



## MgO(111) thin films / Ag(111) : experiments

PHYSICAL REVIEW B 68, 115402 (2003)

#### Atomic and electronic structure of an unreconstructed polar MgO(111) thin film on Ag(111)

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Atomic and electronic structures of a polar surface of MgO formed on Ag(111) was investigated by using reflection high-energy electron-diffraction, Auger-electron spectroscopy, electron energy-loss spectroscopy (EELS), and ultraviolet photoemission spectroscopy (UPS). A rather flat unreconstructed polar MgO(111) 1  $\times$ 1 surface could be grown by alternate adsorption of Mg and O<sub>2</sub> on Ag(111). The stability of the MgO(111) surface was discussed in terms of interaction between Ag and Mg atoms at the interface and charge state of the surface atoms. EELS of this surface did not show a band-gap region, and finite density of states appeared at the Fermi level in UPS. These results suggest that a polar MgO(111) surface was not an insulating surface but a semiconducting or metallic surface.

the substrate. The result of RHEED patterns indicated that the MgO film grew heteroepitaxially on Ag(111). The epitaxial orientation of the MgO film was determined to be  $(111)_{MgO}//(111)_{Ag}$  and  $[1\bar{1}0]_{MgO}//[1\bar{1}0]_{Ag}$ . The halforder streaks did not appear during the growth, showing that the  $(1 \times 1)$  unreconstructed MgO(111) film was grown on Ag(111). Streaks in RHEED patterns indicated that a rather flat (111) surface could be obtained. The RHEED pattern became blurred with increasing film thickness, suggesting that a thick MgO(111) film was unstable.

The in-plane lattice constant of the MgO(111) film was calculated from the spacing between streaks in the RHEED pattern. For the 10-ML-thick MgO(111)/Ag(111), the inplane lattice constant was determined to be  $3.28\pm0.03$  Å,<sup>12</sup> which was  $\pm 10\%$  larger than that of the bulk one (2.97 Å). The in-plane lattice constant was  $3.25\pm0.03$  Å for the 2-ML-thick film and did not change with film thickness, indicating that the expansion was uniform throughout the epitaxial layer. The increase of the in-plane lattice constant

## CONCLUSIONS

The polar catastrophe never happens: polar surfaces are always compensated (no macroscopic polarization through the sample)

Simple recipe to build up structural models of compensated polar surfaces (but reality is often beyond human imagination!)

 Polar surfaces of oxides are extremely sensitive to external conditions (chemical environment, temperature, annealing, etc.)

- ZnO(0001): Zn-vacancy ordering or H adsorption, as a function of environment
- MgO(111): the (2x2) reconstruction is a mixture of two (or more) structure
- Ultra-thin MgO(111) films: exotic phases?

## **1D Polarization (along the surface normal)**



$$\langle \overline{P}(x) \rangle = \frac{1}{L} \int_{0}^{L} dx \, \overline{P}(x) = \frac{1}{L} \Big[ x\overline{P}(x) \Big]_{0}^{L} - \frac{1}{L} \int_{0}^{L} dx \, x \frac{dP(x)}{dx} = \overline{P}(L) + \frac{1}{L} \int_{0}^{x_{s}} dx \, x \overline{\rho}(x) + \frac{1}{L} \int_{x_{s}}^{L} dx \, x \overline{\rho}(x) \\ \xrightarrow{L \to \infty} \overline{P}(x_{s}) + \frac{1}{L} \int_{x_{s}}^{L} dx \, x \, \overline{\rho}(x) = -\int_{-\infty}^{x_{s}} dx \, \overline{\rho}(x) + \int_{x_{s}}^{x_{s}+a} dx \, x \, \overline{\rho}(x) = -\sigma_{s}(x_{s}) + \frac{\overline{\mu}_{B}(x_{s})}{aS} \\ \xrightarrow{L \to \infty} \overline{P}(x_{s}) + \frac{1}{L} \int_{x_{s}}^{L} dx \, x \, \overline{\rho}(x) = -\int_{-\infty}^{x_{s}} dx \, \overline{\rho}(x) + \int_{x_{s}}^{x_{s}+a} dx \, x \, \overline{\rho}(x) = -\sigma_{s}(x_{s}) + \frac{\overline{\mu}_{B}(x_{s})}{aS} \\ \xrightarrow{L \to \infty} \overline{P}(x_{s}) + \frac{1}{L} \int_{x_{s}}^{L} dx \, x \, \overline{\rho}(x) = -\int_{-\infty}^{x_{s}} dx \, \overline{\rho}(x) + \int_{x_{s}}^{x_{s}+a} dx \, x \, \overline{\rho}(x) = -\sigma_{s}(x_{s}) + \frac{\overline{\mu}_{B}(x_{s})}{aS} \\ \xrightarrow{L \to \infty} \overline{P}(x_{s}) + \frac{1}{L} \int_{x_{s}}^{L} dx \, x \, \overline{\rho}(x) = -\int_{-\infty}^{x_{s}} dx \, \overline{\rho}(x) + \int_{x_{s}}^{x_{s}+a} dx \, x \, \overline{\rho}(x) = -\sigma_{s}(x_{s}) + \frac{\overline{\mu}_{B}(x_{s})}{aS} \\ \xrightarrow{L \to \infty} \overline{P}(x_{s}) + \frac{1}{L} \int_{x_{s}}^{L} dx \, x \, \overline{\rho}(x) = -\int_{-\infty}^{x_{s}} dx \, \overline{\rho}(x) + \int_{x_{s}}^{x_{s}+a} dx \, \overline{\rho}(x) = -\sigma_{s}(x_{s}) + \frac{\overline{\mu}_{B}(x_{s})}{aS} \\ \xrightarrow{L \to \infty} \overline{P}(x_{s}) + \frac{1}{L} \int_{x_{s}}^{L} dx \, x \, \overline{\rho}(x) = -\int_{-\infty}^{x_{s}} dx \, \overline{\rho}(x) + \int_{x_{s}}^{x_{s}+a} dx \, \overline{\rho}(x) = -\sigma_{s}(x_{s}) + \frac{\overline{\mu}_{B}(x_{s})}{aS} \\ \xrightarrow{L \to \infty} \overline{P}(x) + \frac{1}{L} \int_{x_{s}}^{L} dx \, x \, \overline{\rho}(x) = -\int_{x_{s}}^{x_{s}+a} dx \, \overline{\rho}(x) + \frac{1}{L} \int_{x_{s}}^{x_{s}+a} dx \, \overline{\rho}(x) + \frac{1}{L} \int_$$

The surface charge at the surface/bulk border is related to the bulk dipole moment computed by choosing this border as the origin of the unit cell

 $Q_S(x_S) = \frac{PB(PS)}{a}$ 

## **Polarization in dielectrics (insulators)**

From the very beginning: Faraday's experience



Electric field between plates and dielectric

$$\sigma_{POL} = \vec{P} \cdot \hat{n} \implies E = \frac{\sigma - \sigma_{POL}}{\varepsilon_0}$$

Amount of polarization charge that is <u>displaced</u> <u>out of the insulator</u> ( $\Omega$  is a volume including the dielectric, *S* the corresponding surface)

$$\int_{\Omega} d\Omega \,\rho_{POL} = \Delta Q_{POL} = -\int_{S} ds \,\vec{P} \cdot \hat{n} = -\int_{\Omega} d\Omega \,\vec{\nabla} \cdot \vec{P}$$
$$\implies \rho_{POL} = -\vec{\nabla} \cdot \vec{P}$$

Macroscopic polarization:

## The MgO(111) (2x2) reconstruction : the oct-O + hex-Mg model

Minimal (two-phase) model : hex-Mg + O-oct So far, the best solution

- Consistent with the observed surface decomposition at very low po
- The hex-Mg to O-oct transformation does not need big matter displacement (add a surface O and relax locally)
- Excellent fit of the GIXS data in a wide (po T) range

#### CONCLUSION

Neither theory nor experience (taken separately) could explain the (2x2) reconstruction in terms of a comprehensive structural model Only the conjunction of the two methods solved the issue, even for a "simple" system like MgO !

Finocchi et al, PRL 2004